INA5006AC1

FOR HIGH CURRENT DRIVE APPLICATION
SILICON PNP EPITAXIAL TYPE

DESCRIPTION

INA5006AC1 is a silicon PNP epitaxial type transistor.
It is designed with high collector current and small $V_{CE(sat)}$.

FEATURE

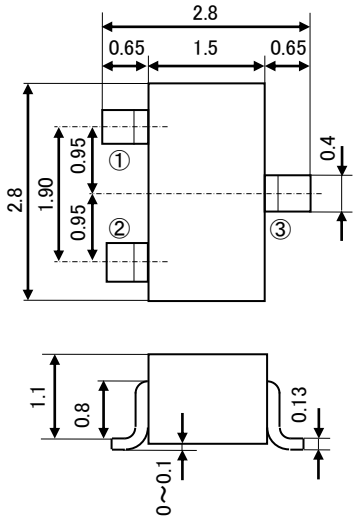
- Super mini package for easy mounting
- High collector current(I_C=−2A)
- Low collector saturation voltage
  ($V_{CE(sat)}$=−0.2Vmax @I_C=−1A、I_B=−33mA)

APPLICATION

Audiovisual apparatus, Relay drive

OUTLINE DRAWING

UNIT : mm



Terminal Connector
①: Base
②: Emitter
③: Collector

JEITA:SC-59
JEDEC: Similar to TO-236

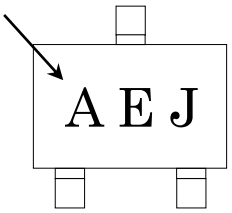
MAXIMUM RATING (Ta=25℃)

SYMBOL	PARAMETER	RATING	UNIT
V_{CEO}	Collector to Emitter voltage	−50	V
V_{CBO}	Collector to Base voltage	−50	V
V_{EBO}	Emitter to Base voltage	−7	V
I_C	Collector current	−2	A
P_C	Collector dissipation	200	mW
		900(*)	
T_j	Junction temperature	+150	℃
T_{stg}	Storage temperature	−55～+150	℃

*Mounted on ceramic board(19mm × 9mm × 1mm)

MARKING

Type Name

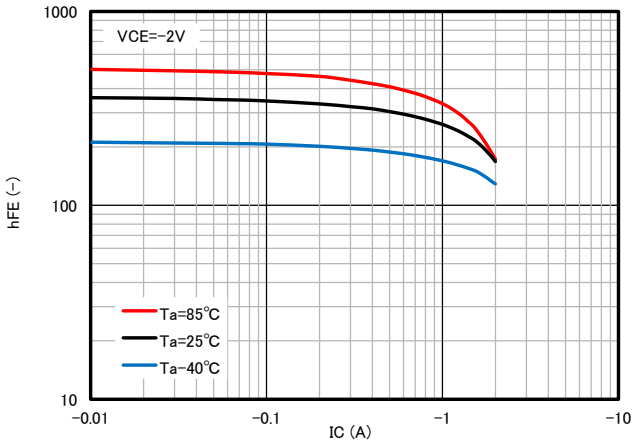


ELECTRICAL CHARACTERISTICS (Ta=25℃)

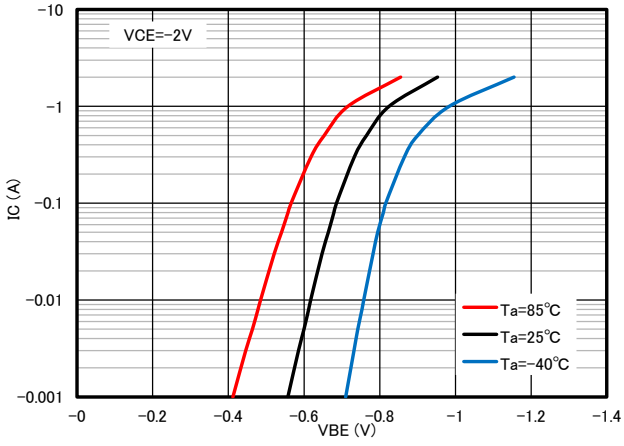
SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
$V_{(BR)CEO}$	C to E breakdown voltage	I_C=−10mA, I_B=0mA	−50	−	−	V
$V_{(BR)CBO}$	C to B breakdown voltage	I_C=−100μA, I_E=0mA	−50	−	−	V
$V_{(BR)EBO}$	E to B breakdown voltage	I_E=−100μA, I_C=0mA	−7	−	−	V
I_{CBO}	Collector cut off current	V_{CB}=−50V, I_E=0mA	−	−	−0.1	μA
I_{EBO}	Emitter cut off current	V_{EB}=−7V, I_C=0mA	−	−	−0.1	μA
h_{FE1}	DC forward current gain1	V_{CE}=−2V, I_C=−300mA	200	−	500	−
h_{FE2}	DC forward current gain2	V_{CE}=−2V, I_C=−1A	100	−	−	−
$V_{CE(sat)}$	C to E saturation voltage	I_C=−1A, I_B=−33mA	−	−	−0.2	V
$V_{BE(sat)}$	B to E saturation voltage	I_C=−1A, I_B=−33mA	−	−	−1.1	V
f_T	Gain bandwidth product	V_{CE}=−2V, I_E=300mA, f=100MHz	−	180	−	MHz
Cob	Collector output capacitance	V_{CB}=−10V, f=1MHz	−	20	−	pF

TYPICAL CHARACTERISTICS

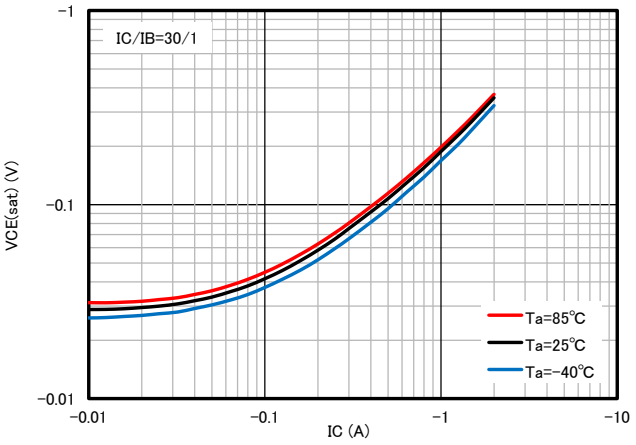
hFE–IC



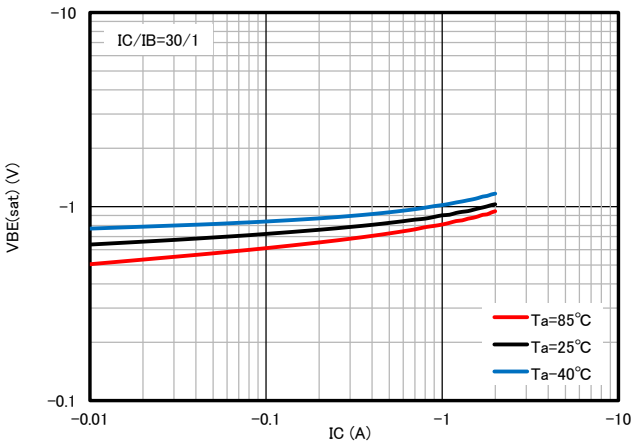
IC–VBE



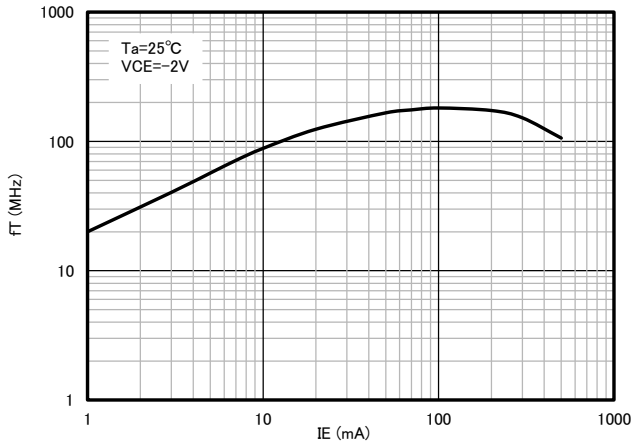
VCE(sat)–IC



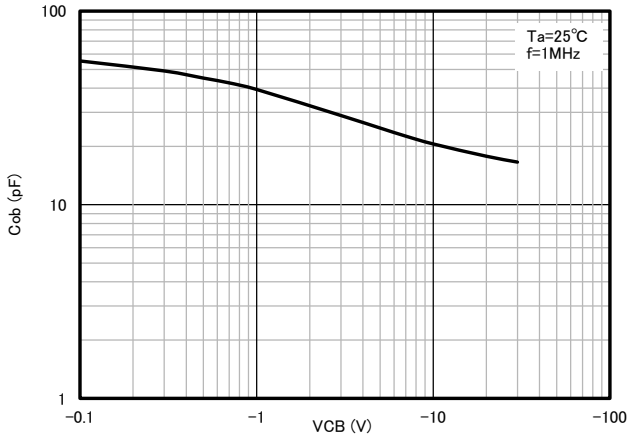
VBE(sat)–IC



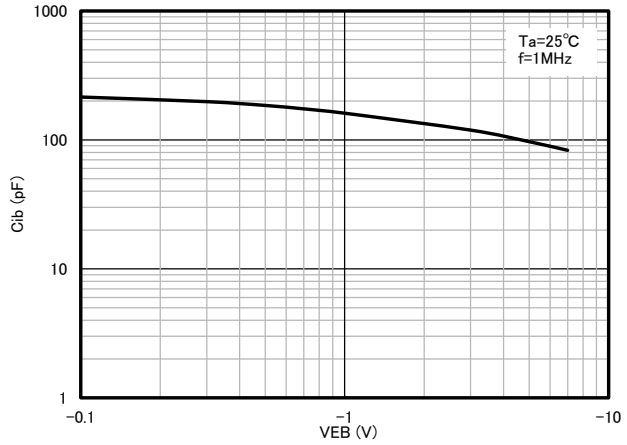
fT–IE



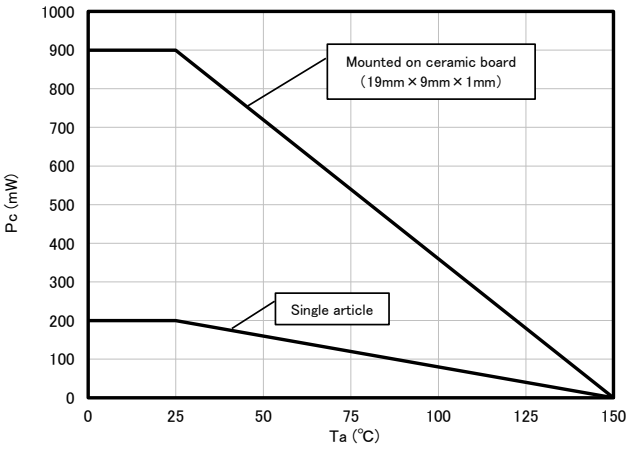
Cob–VCB



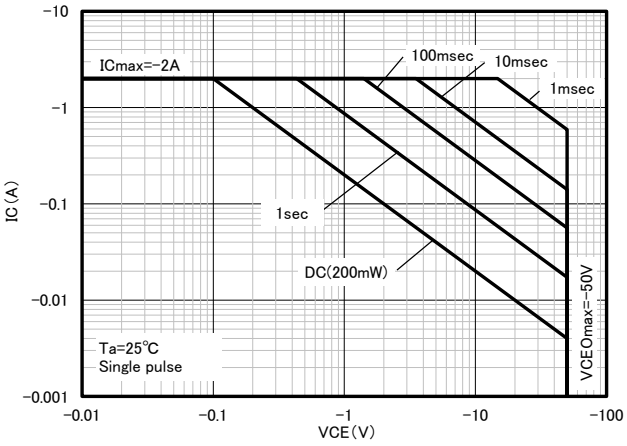
Cib-VEB



Pc-Ta



ASO



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